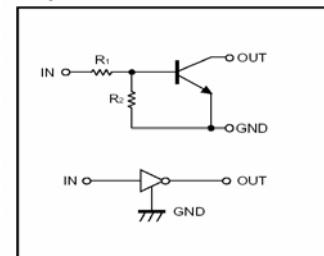


## Features

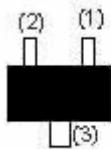
1. Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
2. The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
3. Only the on/off conditions need to be set for operation, making device design easy.

● Equivalent circuit



## PIN CONNECTIONS AND MARKING

**DTC143ZE**

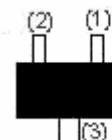


1.IN  
2.GND  
3.OUT

SOT-523

Addreviated symbol: E23

**DTC143ZUA**



1.IN  
2.GND  
3.OUT

SOT-323

Addreviated symbol: E23

**DTC143ZKA**

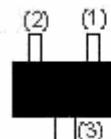


1.IN  
2.GND  
3.OUT

SOT-23-3L

Addreviated symbol: E23

**DTC143ZCA**

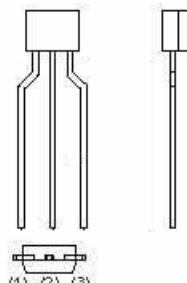


1.IN  
2.GND  
3.OUT

SOT-23

Addreviated symbol: E23

**DTC143ZSA**



1.GND  
2.OUT  
3.IN

TO-92S

**Absolute maximum ratings(Ta=25°C)**

Parameter	Symbol	Limits (DTC143Z□ )					Unit
		E	UA	CA	KA	SA	
Collector-base voltage	V <sub>(BR)CBO</sub>	50					V
Collector-emitter voltage	V <sub>(BR)CEO</sub>	50					V
Emitter-base voltage	V <sub>(BR)EBO</sub>	5					V
Collector current	I <sub>C</sub>	100					mA
Collector Power dissipation	P <sub>C</sub>	150	200	200	300	300	mW
Junction temperature	T <sub>j</sub>	150					°C
Storage temperature	T <sub>stg</sub>	-55~150					°C

**Electrical characteristics (Ta=25°C)**

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V <sub>I(off)</sub>			0.5	V	V <sub>CC</sub> =5V ,I <sub>O</sub> =100μA
	V <sub>I(on)</sub>	1.3				V <sub>O</sub> =0.3V ,I <sub>O</sub> =5 mA
Output voltage	V <sub>O(on)</sub>		0.1	0.3	V	I <sub>O</sub> /I <sub>I</sub> =5mA/0.25mA
Input current	I <sub>I</sub>			1.8	mA	V <sub>I</sub> =5V
Output current	I <sub>O(off)</sub>			0.5	μA	V <sub>CC</sub> =50V ,V <sub>I</sub> =0
DC current gain	G <sub>I</sub>	80				V <sub>O</sub> =5V ,I <sub>O</sub> =10mA
Input resistance	R <sub>I</sub>	3.29	4.7	6.11	KΩ	
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	8	10	12		
Transition frequency	f <sub>T</sub>		250		MHz	V <sub>CE</sub> =10V ,I <sub>E</sub> =-5mA,f=100MHz

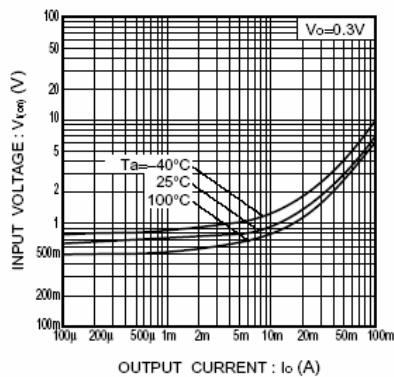
**Typical Characteristics**


Fig.1 Input voltage vs. output current  
(ON characteristics)

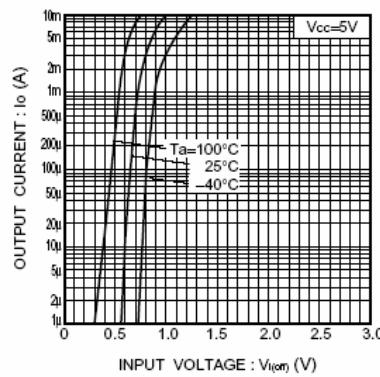


Fig.2 Output current vs. input voltage  
(OFF characteristics)

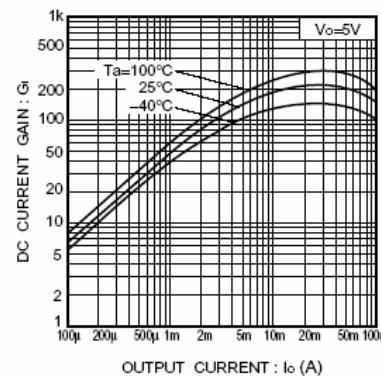


Fig.3 DC current gain vs. output current

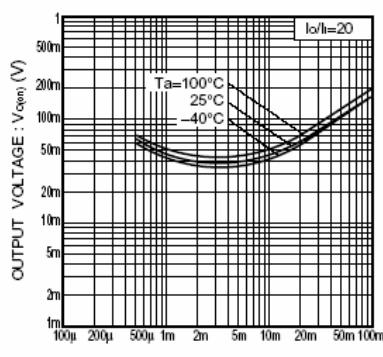


Fig.4 Output voltage vs. output current